

國立彰化師範大學 100 學年度碩士班招生考試試題

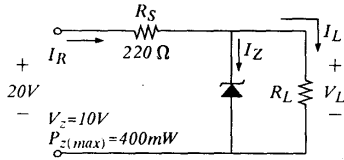
系所： 車輛科技研究所

科目： 電子學

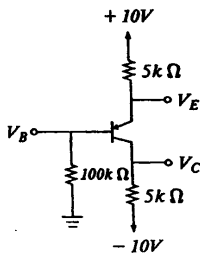
☆☆請在答案紙上作答☆☆

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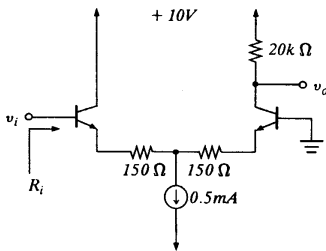
1. Determine V_L , I_L , I_Z and I_R for the following circuit if $R_L=280\Omega$. (20%)



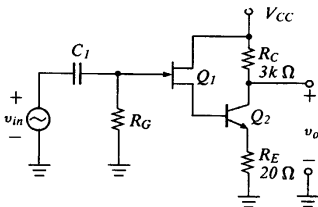
2. Determine α , β and V_C for the transistor in the following circuit if $V_B=1.0V$ and $V_E=1.7V$. (20%)



3. Assume each transistor in figure has $\beta=80$ and $r_e=100\Omega$. Find
 (1) the voltage gain of the amplifier
 (2) the input resistance of the amplifier(20%)



4. The two transistor amplifiers shown in the following figure combine an FET and a BJT to achieve both a high input impedance and a large voltage gain. Determine the voltage gain v_o/v_i of the amplifier by considering Q_1 with $g_m=1ms$, $r_\pi=1k\Omega$ and $\beta=120$. (20%)



5. Calculate v_o (biased DC value) in the bipolar differential amplifier circuit shown in the following figure. (20%)

